NSN 5961-01-054-6496

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Inclosure Material:	
Metal	
Overall Length:	
Between 0.328 inches and 0.380 inches	
Overall Diameter:	
Between 0.715 inches and 0.740 inches	
Internal Configuration:	
Field effect	
Electrode Internally-electrically Connected To Case:	
Collector	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, co	ellector-to-emitter, base open and 12.0
breakdown voltage, emitter-to-base, collector open	
Current Rating Per Characteristic:	
7.00 amperes base current, dc and 15.00 amperes collector current, dc	
Power Rating Per Characteristic:	
115.0 watts total power dissipation	
Special Features:	
Junction pattern arrangement: npn	
Terminal Type And Quantity:	
3 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	